# 74HC3G14-Q100; 74HCT3G14-Q100

# **Triple inverting Schmitt trigger**

Rev. 3 — 1 February 2019

**Product data sheet** 

### 1. General description

The 74HC3G14-Q100; 74HCT3G14-Q100 is a triple inverter with Schmitt-trigger inputs. Inputs include clamp diodes that enable the use of current limiting resistors to interface inputs to voltages in excess of  $V_{CC}$ . Schmitt trigger inputs transform slowly changing input signals into sharply defined jitter-free output signals.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

### 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- · Complies with JEDEC standard no. 7A
- Wide supply voltage range from 2.0 V to 6.0 V
- Input levels:
  - For 74HC3G14-Q100: CMOS level
  - For 74HCT3G14-Q100: TTL level
- · High noise immunity
- · Low power dissipation
- · Balanced propagation delays
- Unlimited input rise and fall times
- Multiple package options
- ESD protection:
  - MIL-STD-883, method 3015 exceeds 2000 V
  - HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0  $\Omega$ )

# 3. Applications

- Wave and pulse shaper for highly noisy environments
- Astable multivibrators
- · Monostable multivibrators

# 4. Ordering information

### **Table 1. Ordering information**

Type number	Package	ackage						
	Temperature range	Name	Description	Version				
74HC3G14DP-Q100	-40 °C to +125 °C	TSSOP8	plastic thin shrink small outline package; 8 leads;	SOT505-2				
74HCT3G14DP-Q100			body width 3 mm; lead length 0.5 mm					
74HC3G14DC-Q100	-40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package;	SOT765-1				
74HCT3G14DC-Q100			8 leads; body width 2.3 mm					



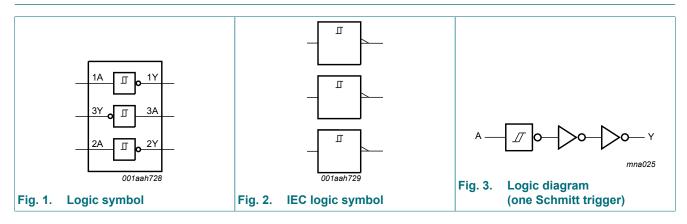
# 5. Marking

### Table 2. Marking

Type number	Marking code [1]
74HC3G14DP-Q100	H14
74HCT3G14DP-Q100	T14
74HC3G14DC-Q100	H14
74HCT3G14DC-Q100	T14

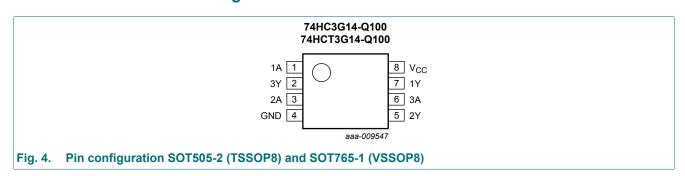
<sup>[1]</sup> The pin 1 indicator is located on the lower left corner of the device, below the marking code.

# 6. Functional diagram



# 7. Pinning information

## 7.1. Pinning



### 7.2. Pin description

Table 3. Pin description

Symbol	Pin	Description
1A, 2A, 3A	1, 3, 6	data input
GND	4	ground (0 V)
1Y, 2Y, 3Y	7, 5, 2	data output
V <sub>CC</sub>	8	supply voltage

## 8. Functional description

### **Table 4. Function table**

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level.$ 

Input	Output
nA	nY
L	Н
Н	L

# 9. Limiting values

### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+7.0	V
I <sub>IK</sub>	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$ [1]	-	±20	mA
I <sub>OK</sub>	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$ [1]	-	±20	mA
I <sub>O</sub>	output current	$V_{O} = -0.5 \text{ V to } V_{CC} + 0.5 \text{ V}$ [1]	-	±25	mA
I <sub>CC</sub>	supply current	[1]	-	+50	mA
I <sub>GND</sub>	ground current	[1]	-50	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	[2]	-	300	mW

<sup>1]</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

# 10. Recommended operating conditions

### Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	74HC3G14-Q100		74HCT3G14-Q100			Unit	
			Min	Тур	Max	Min	Тур	Max	
V <sub>CC</sub>	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
$V_{O}$	output voltage		0	-	V <sub>CC</sub>	0	-	$V_{CC}$	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	-40	+25	+125	°C

<sup>2]</sup> For TSSOP8 package: above 55 °C the value of P<sub>tot</sub> derates linearly with 2.5 mW/K. For VSSOP8 package: above 110 °C the value of P<sub>tot</sub> derates linearly with 8 mW/K.

# 11. Static characteristics

### **Table 7. Static characteristics**

Voltages are referenced to GND (ground = 0 V). All typical values are measured at  $T_{amb}$  = 25 °C.

Symbol	Parameter	Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC3G	14-Q100				•	•		•		
V <sub>OH</sub>	HIGH-level	$V_I = V_{T+}$ or $V_{T-}$								
	output voltage	I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 6.0 V	5.9	6.0	-	5.9	-	5.9	-	V
		$I_{O}$ = -4.0 mA; $V_{CC}$ = 4.5 V	4.18	4.32	-	4.13	-	3.7	-	V
		I <sub>O</sub> = -5.2 mA; V <sub>CC</sub> = 6.0 V	5.68	5.81	-	5.63	-	5.2	-	V
V <sub>OL</sub>	LOW-level	$V_I = V_{T+}$ or $V_{T-}$								
	output voltage	I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.0 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 6.0 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 4.5 V	-	0.15	0.26	-	0.33	-	0.4	V
		I <sub>O</sub> = 5.2 mA; V <sub>CC</sub> = 6.0 V	-	0.16	0.26	-	0.33	-	0.4	V
I <sub>I</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	-	±1.0	-	±1.0	μΑ
I <sub>CC</sub>	supply current	per input pin; $V_{CC} = 6.0 \text{ V}$ ; $V_I = V_{CC}$ or GND; $I_O = 0 \text{ A}$	-	-	1.0	-	10	-	20	μΑ
C <sub>I</sub>	input capacitance		-	2.0	-	-	-	-	-	pF
<b>74HCT3</b>	G14-Q100	1	'		'	'	-	'	'	
V <sub>OH</sub>	HIGH-level	$V_I = V_{T+}$ or $V_{T-}$								
	output voltage	I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 4.5 V	4.18	4.32	-	4.13	-	3.7	-	V
V <sub>OL</sub>	LOW-level	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>								
	output voltage	I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 4.5 V	-	0.15	0.26	-	0.33	-	0.4	V
I <sub>I</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±0.1	-	±1.0	-	±1.0	μΑ
I <sub>CC</sub>	supply current	per input pin; $V_{CC} = 5.5 \text{ V}$ ; $V_I = V_{CC}$ or GND; $I_O = 0 \text{ A}$	-	-	1.0	-	10	-	20	μΑ
ΔI <sub>CC</sub>	additional supply current	per input; $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V};$ $V_{I} = V_{CC} - 2.1 \text{ V}; I_{O} = 0 \text{ A}$	-	-	300	-	375	-	410	μΑ
Cı	input capacitance		-	2.0	-	-	-	-	-	pF

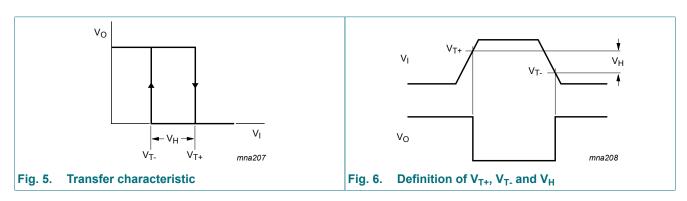
### 11.1. Transfer characteristics

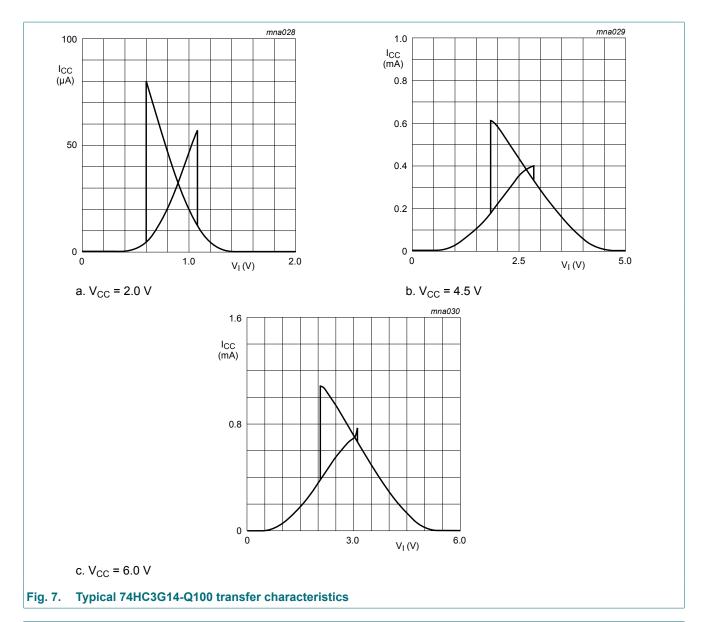
**Table 8. Transfer characteristics** 

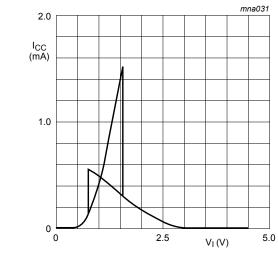
Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 10.

Symbol	Parameter	Conditions		25 °C			-40 °C to +125 °C			
			Min	Тур	Max	Min	Max (85 °C)	Max (125 °C)		
74HC3G	14-Q100									
V <sub>T+</sub>	positive-going	see <u>Fig. 5</u> , <u>Fig. 6</u>								
	threshold voltage	V <sub>CC</sub> = 2.0 V	1.00	1.18	1.50	1.00	1.50	1.50	V	
		V <sub>CC</sub> = 4.5 V	2.30	2.60	3.15	2.30	3.15	3.15	V	
		V <sub>CC</sub> = 6.0 V	3.00	3.46	4.20	3.00	4.20	4.20	V	
V <sub>T-</sub>	negative-going	see Fig. 5, Fig. 6								
	threshold voltage	V <sub>CC</sub> = 2.0 V	0.30	0.60	0.90	0.30	0.90	0.90	V	
		V <sub>CC</sub> = 4.5 V	1.13	1.47	2.00	1.13	2.00	2.00	V	
		V <sub>CC</sub> = 6.0 V	1.50	2.06	2.60	1.50	2.60	2.60	V	
V <sub>H</sub>	hysteresis voltage	(V <sub>T+</sub> - V <sub>T-</sub> ); see <u>Fig. 5</u> , <u>Fig. 6</u> and <u>Fig. 7</u>								
		V <sub>CC</sub> = 2.0 V	0.30	0.60	1.00	0.30	1.00	1.00	V	
		V <sub>CC</sub> = 4.5 V	0.60	1.13	1.40	0.60	1.40	1.40	V	
		V <sub>CC</sub> = 6.0 V	0.80	1.40	1.70	0.80	1.70	1.70	V	
74HCT3	G14-Q100		•			'		1		
V <sub>T+</sub>	positive-going	see <u>Fig. 5</u> , <u>Fig. 6</u>								
	threshold voltage	V <sub>CC</sub> = 4.5 V	1.20	1.58	1.90	1.20	1.90	1.90	V	
		V <sub>CC</sub> = 5.5 V	1.40	1.78	2.10	1.40	2.10	2.10	V	
V <sub>T-</sub>	negative-going	see Fig. 5, Fig. 6								
	threshold voltage	V <sub>CC</sub> = 4.5 V	0.50	0.87	1.20	0.50	1.20	1.20	V	
		V <sub>CC</sub> = 5.5 V	0.60	1.11	1.40	0.60	1.40	1.40	V	
V <sub>H</sub>	hysteresis voltage	(V <sub>T+</sub> - V <sub>T-</sub> ); see <u>Fig. 5</u> , <u>Fig. 6</u> and <u>Fig. 8</u>								
		V <sub>CC</sub> = 4.5 V	0.40	0.71	-	0.40	-	-	V	
		V <sub>CC</sub> = 5.5 V	0.40	0.67	-	0.40	-	-	V	

### 11.2. Transfer characteristics waveforms







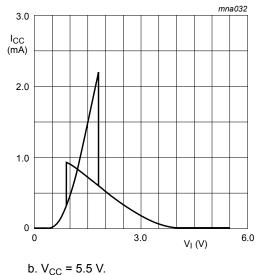


Fig. 8. Typical 74HCT3G14-Q100 transfer characteristics

**Product data sheet** 

a.  $V_{CC} = 4.5 \text{ V}$ .

# 12. Dynamic characteristics

### **Table 9. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 10.

	·= ·								
Parameter	Conditions		25 °C			-40 °C to +125 °C			Unit
			Min	Тур	Max	Min	Max (85 °C)	Max (125 °C)	
14-Q100		'							
propagation delay	nA to nY; see Fig. 9	[1]							
	V <sub>CC</sub> = 2.0 V		-	53	125	-	155	190	ns
	V <sub>CC</sub> = 4.5 V		-	16	25	-	31	38	ns
	V <sub>CC</sub> = 6.0 V		-	13	21	-	26	32	ns
transition time	nY; see Fig. 9	[2]							
	V <sub>CC</sub> = 2.0 V		-	20	75	-	95	110	ns
	V <sub>CC</sub> = 4.5 V		-	7	15	-	19	22	ns
	V <sub>CC</sub> = 6.0 V		-	5	13	-	16	19	ns
power dissipation capacitance	$V_I$ = GND to $V_{CC}$	[3]	-	10	-	-	-	-	pF
G14-Q100					ı		'	'	
propagation delay	nA to nY; V <sub>CC</sub> = 4.5 V; see <u>Fig. 9</u>	[1]	-	21	32	-	40	48	ns
transition time	nY; V <sub>CC</sub> = 4.5 V; see <u>Fig. 9</u>	[2]	-	6	15	-	19	22	ns
power dissipation capacitance	$V_I$ = GND to $V_{CC}$ - 1.5 V	[3]	-	10	-	-	-	-	pF
	propagation delay  transition time  power dissipation capacitance  G14-Q100  propagation delay  transition time  power dissipation	propagation delay $V_{CC} = 2.0 \text{ V}$ $V_{CC} = 4.5 \text{ V}$ $V_{CC} = 6.0 \text{ V}$ transition time $V_{CC} = 4.5 \text{ V}$ $V_{CC} = 4.5 \text{ V}$ $V_{CC} = 6.0 \text{ V}$ power dissipation capacitance $V_{CC} = 6.0 \text{ V}$ propagation delay $V_{CC} = 6.0 \text{ V}$	propagation delay $\begin{array}{c} \text{nA to nY; see } \underline{\text{Fig. 9}} & \text{[1]} \\ \hline V_{CC} = 2.0 \text{ V} \\ \hline V_{CC} = 4.5 \text{ V} \\ \hline V_{CC} = 6.0 \text{ V} \\ \hline \text{transition time} & \text{nY; see } \underline{\text{Fig. 9}} & \text{[2]} \\ \hline V_{CC} = 2.0 \text{ V} \\ \hline V_{CC} = 4.5 \text{ V} \\ \hline V_{CC} = 4.5 \text{ V} \\ \hline V_{CC} = 6.0 \text{ V} \\ \hline \end{array}$ $\begin{array}{c} \text{power dissipation capacitance} & \text{NA to nY; V}_{CC} = 6.0 \text{ V} \\ \hline \end{array}$ $\begin{array}{c} \text{propagation delay} & \text{nA to nY; V}_{CC} = 4.5 \text{ V; see } \underline{\text{Fig. 9}} \\ \hline \text{transition time} & \text{nY; V}_{CC} = 4.5 \text{ V; see } \underline{\text{Fig. 9}} \\ \hline \end{array}$ $\begin{array}{c} \text{power dissipation delay} & \text{nA to nY; V}_{CC} = 4.5 \text{ V; see } \underline{\text{Fig. 9}} \\ \hline \end{array}$				$ \begin{array}{ c c c c c c c c } \hline \textbf{Min} & \textbf{Typ} & \textbf{Max} & \textbf{Min} \\ \hline                                  $		$ \begin{array}{ c c c c c c c c c c c c c c c c c c c$

- tpd is the same as tPLH and tPHL
- $t_t$  is the same as  $t_{TLH}$  and  $t_{THL}$   $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_0)$  where:

 $f_i$  = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

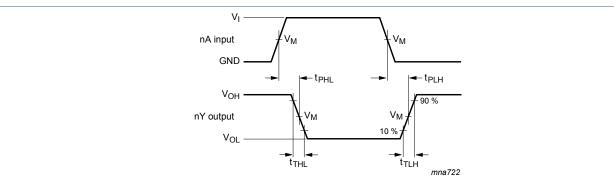
C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$  = sum of the outputs.

### 12.1. Waveforms and test circuit



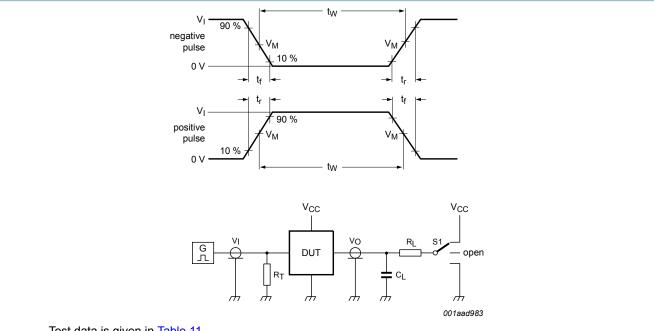
Measurement points are given in Table 10.

V<sub>OL</sub> and V<sub>OH</sub> are typical voltage output levels that occur with the output load.

Fig. 9. The data input (nA) to output (nY) propagation delays and output transition times

**Table 10. Measurement points** 

Туре	Input	Output
	V <sub>M</sub>	V <sub>M</sub>
74HC3G14-Q100	0.5V <sub>CC</sub>	0.5V <sub>CC</sub>
74HCT3G14-Q100	1.3 V	1.3 V



Test data is given in Table 11.

Definitions for test circuit:

 $R_T$  = Termination resistance should be equal to output impedance  $Z_0$  of the pulse generator.

 $C_L$  = Load capacitance including jig and probe capacitance.

 $R_L$  = Load resistance.

S1 = Test selection switch.

Fig. 10. Test circuit for measuring switching times

Table 11. Test data

Туре	Input I		Load	S1 position	
	V <sub>I</sub>	t <sub>r</sub> , t <sub>f</sub>	CL	$R_L$	t <sub>PHL</sub> , t <sub>PLH</sub>
74HC3G14-Q100	GND to V <sub>CC</sub>	≤ 6 ns	50 pF	1 kΩ	open
74HCT3G14-Q100	GND to 3.0 V	≤ 6 ns	50 pF	1 kΩ	open

# 13. Application information

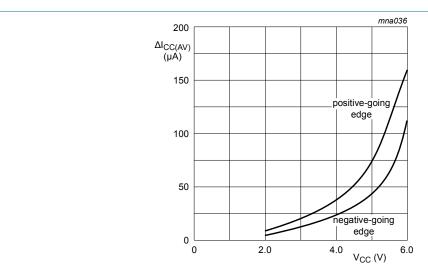
The slow input rise and fall times cause additional power dissipation, which can be calculated using the following formula:

 $P_{add} = f_i \times (t_r \times \Delta I_{CC(AV)} + t_f \times \Delta I_{CC(AV)}) \times V_{CC}$  where:

- P<sub>add</sub> = additional power dissipation (μW);
- f<sub>i</sub> = input frequency (MHz);
- t<sub>r</sub> = input rise time (ns); 10 % to 90 %;
- t<sub>f</sub> = input fall time (ns); 90 % to 10 %;
- ΔI<sub>CC(AV)</sub> = average additional supply current (µA).

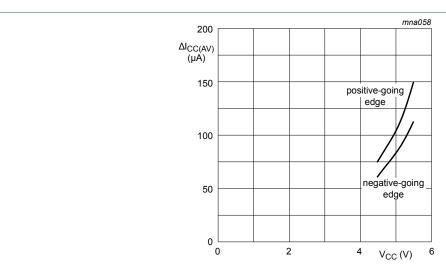
Δl<sub>CC(AV)</sub> differs with positive or negative input transitions, as shown in Fig. 11 and Fig. 12.

An example of a relaxation circuit using the 74HC3G14-Q100/74HCT3G14-Q100 is shown in Fig. 13.



Linear change of V<sub>I</sub> between 0.1V<sub>CC</sub> to 0.9V<sub>CC</sub>.

Fig. 11.  $\Delta I_{CC(AV)}$  as a function of  $V_{CC}$  for 74HC3G14-Q100

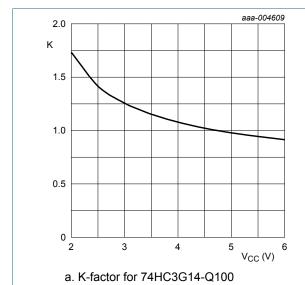


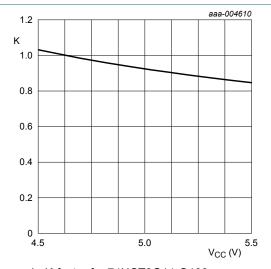
Linear change of  $V_I$  between  $0.1V_{CC}$  to  $0.9V_{CC}$ .

Fig. 12.  $\Delta I_{CC(AV)}$  as a function of  $V_{CC}$  for 74HCT3G14-Q100

For 74HC3G14-Q100:  $f = \frac{1}{T} \approx \frac{1}{0.8 \times \text{RC}}$ For 74HCT3G14-Q100:  $f = \frac{1}{T} \approx \frac{1}{0.67 \times \text{RC}}$ For K-factor, see Fig. 14

Fig. 13. Relaxation oscillator





b. K-factor for 74HCT3G14-Q100

Fig. 14. Typical K-factor for relaxation oscillator

# 14. Package outline

TSSOP8: plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm SOT505-2

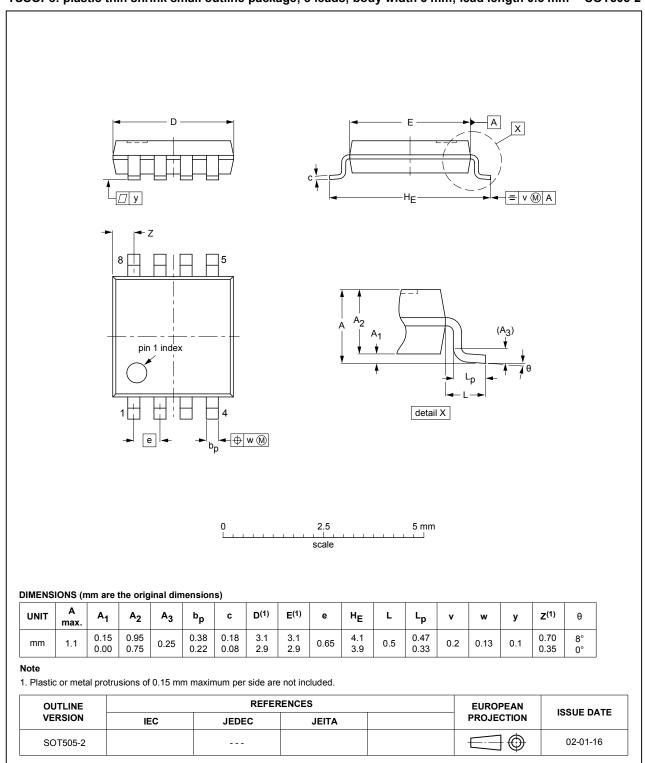


Fig. 15. Package outline SOT505-2 (TSSOP8)

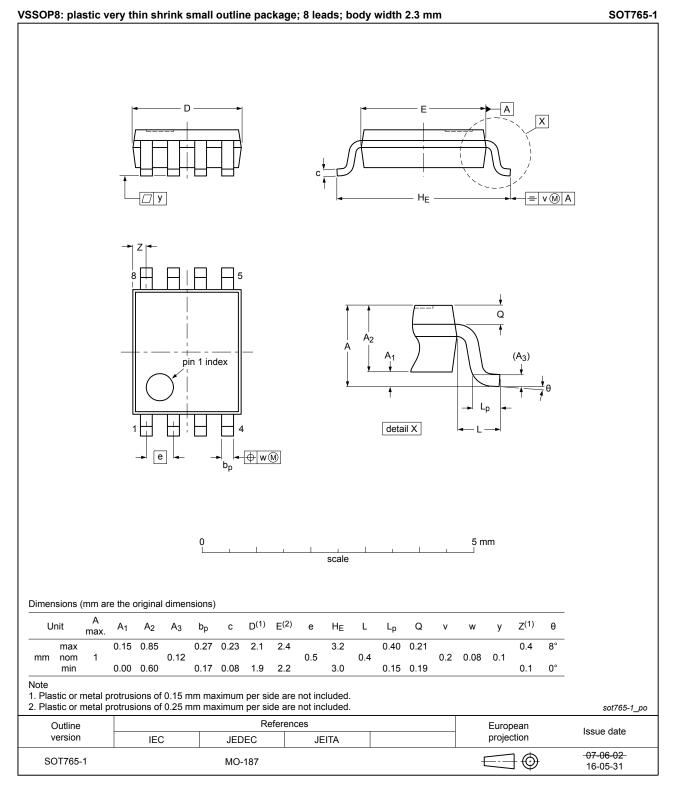


Fig. 16. Package outline SOT765-1 (VSSOP8)

# 15. Abbreviations

### **Table 12. Abbreviations**

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MIL	Military
MM	Machine Model
TTL	Transistor-Transistor Logic

# 16. Revision history

### Table 13. Revision history

Table 10. Revision mistory						
Document ID	Release date	Data sheet status	Change notice	Supersedes		
74HC_HCT3G14_Q100 v.3	20190201	Product data sheet	-	74HC_HCT3G14_Q100 v.2		
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Package outline drawing <u>SOT765-1</u> (VSSOP8) updated.</li> </ul>					
74HC_HCT3G14_Q100 v.2	20131209	Product data sheet	-	74HC_HCT3G14_Q100 v.1		
Modifications:	Fig. 14 added (typical K-factor for relaxation oscillator).					
74HC_HCT3G14_Q100 v.1	20131115	Product data sheet	-	-		

### 17. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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